L Number	Hits	Search Text	DB	Time stamp
1	1	257/\$.ccls. and ((metal NEAR gate NEAR (layer film)) WITH (thermal	USPAT;	2003/01/16 11:35
		NEAR oxide))	US-PGPUB;	
			EPO; JPO;	
			IBM_TDB	
2	5	257/\$.ccls. and ((metal NEAR gate) NEAR5 (thermal NEAR oxide))	USPAT;	2003/01/16 11:38
	٠	·	US-PGPUB;	
			EPO; JPO;	
			IBM_TDB	
3	6	257/\$.ccls. and ((metal NEAR gate) WITH (thermal NEAR oxide))	USPAT;	2003/01/16 11:39
			US-PGPUB;	
			EPO; JPO;	
			IBM_TDB	
4	3101	257/\$.ccls. and (metal NEAR gate)	USPAT;	2003/01/16 11:45
			US-PGPUB;	
			EPO; JPO;	
			IBM_TDB	
5	273	(257/\$.ccls. and (metal NEAR gate)) and (thermal NEAR oxide)	USPAT;	2003/01/16 11:45
			US-PGPUB;	
			EPO; JPO;	
			IBM_TDB	
6	1	((257/\$.ccls. and (metal NEAR gate)) and (thermal NEAR oxide)) and	USPAT;	2003/01/16 11:45
		(pre-metal NEAR dielectric)	US-PGPUB;	
			EPO; JPO;	
			IBM_TDB	
7	172241	257/\$.ccls.	USPAT;	2003/01/16 11:44
			US-PGPUB;	
			EPO; JPO;	
	_		IBM_TDB	2000/01/15 11 15
10	1	((257/\$.ccls. and (pre-metal NEAR dielectric)) and (metal NEAR gate))	USPAT;	2003/01/16 11:45
		and (thermal NEAR oxide)	US-PGPUB;	
			EPO; JPO;	
_	_		IBM_TDB	2002/01/16 11 16
9	2	(257/\$.ccls. and (pre-metal NEAR dielectric)) and (metal NEAR gate)	USPAT;	2003/01/16 11:46
			US-PGPUB;	
			EPO; JPO;	
		257/0 1 1/ 13/DAD 11 1 1/3	IBM_TDB	2002/01/16 11 45
8	49	257/\$.ccls. and (pre-metal NEAR dielectric)	USPAT;	2003/01/16 11:47
			US-PGPUB;	
			EPO; JPO;	
1		1	IBM TDB	1